Static Electrical Characteristics @ $T_J = 25$ °C (unless otherwise specified)

| | Parameter | Min. | Тур. | Max. | Units | Conditions |
|---------------------------------|--------------------------------------|------|-------|------|-------|---|
| V _{(BR)DSS} | Drain-to-Source Breakdown Voltage | 60 | | | V | $V_{GS} = 0V, I_D = 250\mu A$ |
| $\Delta V_{(BR)DSS}/\Delta T_J$ | Breakdown Voltage Temp. Coefficient | | 0.062 | | V/°C | Reference to 25°C, I _D = 1mA |
| R _{DS(on)} | Static Drain-to-Source On-Resistance | | | 16.5 | mΩ | $V_{GS} = 10V, I_D = 31A \ \oplus$ |
| $V_{GS(th)}$ | Gate Threshold Voltage | 2.0 | | 4.0 | V | $V_{DS} = V_{GS}$, $I_D = 250\mu A$ |
| gfs | Forward Transconductance | 24 | | | S | $V_{DS} = 25V, I_{D} = 31A^{\textcircled{4}}$ |
| I _{DSS} | Drain-to-Source Leakage Current | | | 25 | μΑ | $V_{DS} = 60V, V_{GS} = 0V$ |
| | | | | 250 | 1 | $V_{DS} = 48V, V_{GS} = 0V, T_{J} = 150^{\circ}C$ |
| I _{GSS} | Gate-to-Source Forward Leakage | | | 100 | nA | V _{GS} = 20V |
| | Gate-to-Source Reverse Leakage | | | -100 | | V _{GS} = -20V |

Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

| Q_g | Total Gate Charge | | | 67 | | I _D = 51A |
|---------------------|---------------------------------|--|------|----|----|--|
| $\overline{Q_gs}$ | Gate-to-Source Charge | | | 18 | nC | $V_{DS} = 48V$ |
| Q_{gd} | Gate-to-Drain ("Miller") Charge | | | 25 | | V _{GS} = 10V, See Fig.6 and 13 ⁴ |
| t _{d(on)} | Turn-On Delay Time | | 13 | | | $V_{DD} = 30V$ |
| t _r | Rise Time | | 97 | | | I _D = 51A |
| t _{d(off)} | Turn-Off Delay Time | | 40 | | ns | $R_G = 9.1\Omega$ |
| t _f | Fall Time | | 57 | | | $R_D = 0.6\Omega$, See Fig.10 \oplus |
| L _D | Internal Drain Inductance | | 4.5 | | nH | Between lead, 6mm (0.25in.) |
| L _S | Internal Source Inductance | | 7.5 | | | Between lead, and center of die contact |
| C _{iss} | Input Capacitance | | 1812 | | | V _{GS} = 0V |
| Coss | Output Capacitance | | 393 | | pF | $V_{DS} = 25V$ |
| C _{rss} | Reverse Transfer Capacitance | | 103 | | | f = 1.0MHz, See Fig.5 |

Diode Characteristics

| | Parameter | Min. | Тур. | Max. | Units | Conditions | |
|-----------------|---------------------------|-----------|--|------|-------|--|--|
| Is | Continuous Source Current | | | 55 | | MOSFET symbol | |
| | (Body Diode) | | | | Α | showing the | |
| I _{SM} | Pulsed Source Current | | | 220 | | integral reverse | |
| | (Body Diode) ① | | | | | p-n junction diode. | |
| V_{SD} | Diode Forward Voltage | | | 2.5 | V | $T_J = 25$ °C, $I_S = 51A$, $V_{GS} = 0V$ ④ | |
| t _{rr} | Reverse Recovery Time | | 70 | 105 | ns | T _J = 25°C, I _F = 51A | |
| Q _{rr} | Reverse Recovery Charge | | 146 | 219 | nC | di/dt = 100A/µs ④ | |
| t _{on} | Forward Turn-On Time | Intrinsic | Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD) | | | | |

Notes:

- @ Starting T_J = 25°C, L = 89 $\mu H,~R_G$ = 25 $\Omega,~I_{AS}$ = 51A. (See Figure 12)
- $\label{eq:local_spin_spin} \ensuremath{ \Im } \ensuremath{ \mbox{ I_{SD}} \le 51$A, di/dt} \le 227\mbox{A/\mu s, V_{DD}} \le V_{(BR)DSS}, \ensuremath{ T_J$} \le 175\ensuremath{\,^{\circ}\mbox{C}}$
- 4 Pulse width \leq 300 μ s; duty cycle \leq 2%.

Qualification Information[†]

| Qualification Level | | Automotive (per AEC-Q101) †† | | | |
|----------------------------|----------------------|---|---|--|--|
| | | Comments: This part number(s) passed Automotive qualification IR's Industrial and Consumer qualification level is granted b extension of the higher Automotive level. | | | |
| Moisture Sensitivity Level | | 3L-TO-220 | N/A | | |
| | Machine Model | Class M3(+/- 400V) ^{†††} (per AEC-Q101-002) | | | |
| ESD | Human Body Model | Class H1B(+/- 1000V) ^{†††} (per AEC-Q101-001) | | | |
| | Charged Device Model | | Class C5(+/- 2000V) ^{†††} (per AEC-Q101-005) | | |
| RoHS Compliant | | Yes | | | |

[†] Qualification standards can be found at International Rectifier's web site: http://www.irf.com/

^{††} Exceptions (if any) to AEC-Q101 requirements are noted in the qualification report.

^{†††} Highest passing voltage

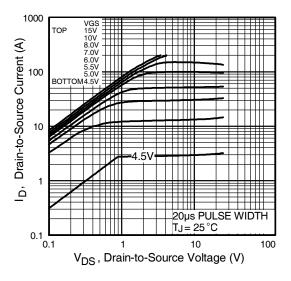


Fig 1. Typical Output Characteristics

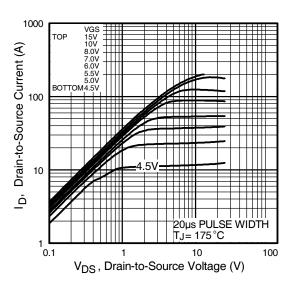


Fig 2. Typical Output Characteristics

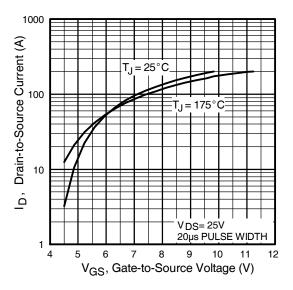


Fig 3. Typical Transfer Characteristics

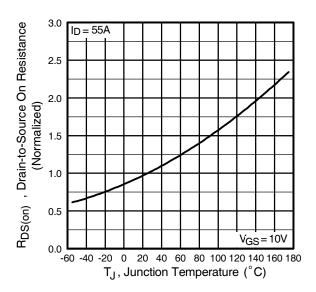


Fig 4. Normalized On-Resistance Vs. Temperature

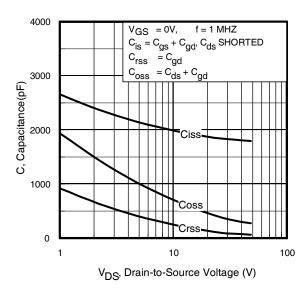


Fig 5. Typical Capacitance Vs. Drain-to-Source Voltage

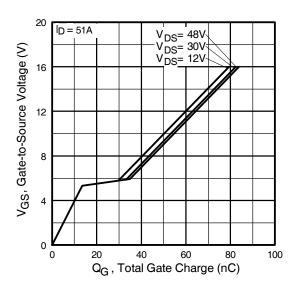


Fig 6. Typical Gate Charge Vs. Gate-to-Source Voltage

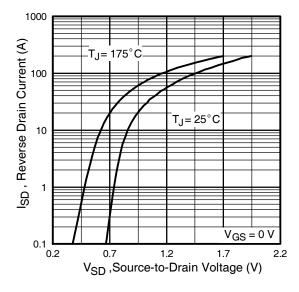


Fig 7. Typical Source-Drain Diode Forward Voltage

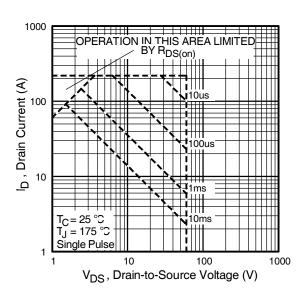


Fig 8. Maximum Safe Operating Area

International **IOR** Rectifier

AUIRFZ44V

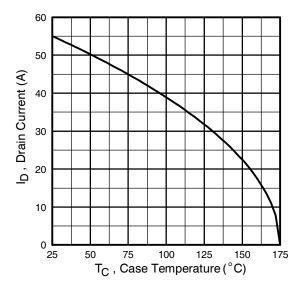


Fig 9. Maximum Drain Current Vs.
Case Temperature

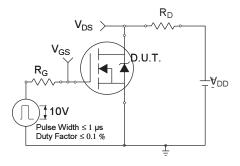


Fig 10a. Switching Time Test Circuit

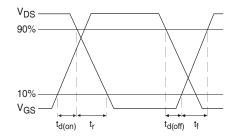


Fig 10b. Switching Time Waveforms

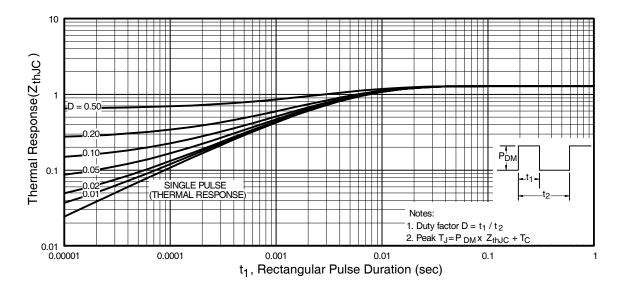


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case

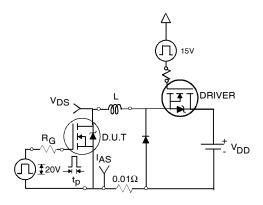


Fig 12a. Unclamped Inductive Test Circuit

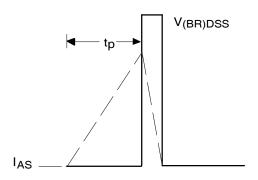


Fig 12b. Unclamped Inductive Waveforms

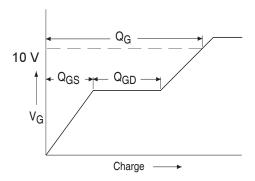


Fig 13a. Basic Gate Charge Waveform

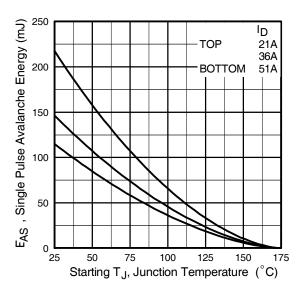


Fig 12c. Maximum Avalanche Energy Vs. Drain Current

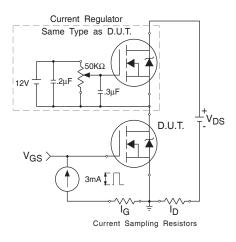
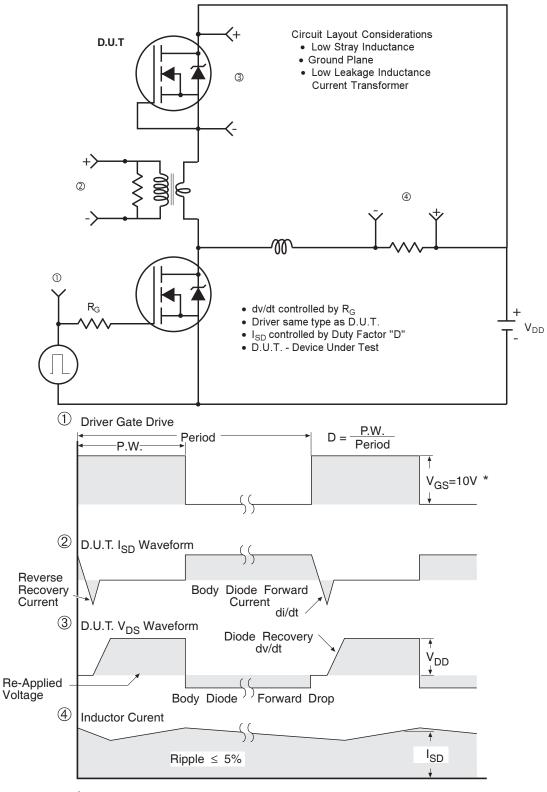


Fig 13b. Gate Charge Test Circuit

Peak Diode Recovery dv/dt Test Circuit

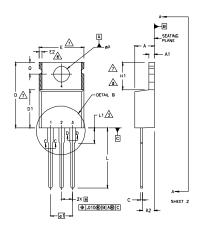


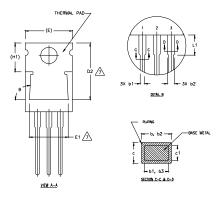
* V_{GS} = 5V for Logic Level Devices

Fig 14. For N-Channel HEXFETS

TO-220AB Package Outline

Dimensions are shown in millimeters (inches)





NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5 M- 1994. DIMENSIONS ARE SHOWN IN INCHES [MILLIMETERS].

- DIMENSIONS ARE SHOWN IN INCHES [MILLUME LERS], LEAD DIMENSION AND FINISH UNCONTROLLED IN L1.
 DIMENSION D & E DO NOT INCLUDE MOLD FLASH, MOLD FLASH
 SHALL NOT EXCEED ...005" (0.127) PER SIDE, THESE DIMENSIONS ARE
 MEASURED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY,
 DIMENSION D1 & c1 APPLY TO BASE METAL ONLY,
 CONTROLAND DIMENSIONAL MOUTERS.
- CONTROLLING DIMENSION ; INCHES,
- THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS E,H1,D2 & E1
- DIMENSION E2 X H1 DEFINE A ZONE WHERE STAMPING AND SINGULATION IRREGULARITIES ARE ALLOWED.

| | | ISIONS | | | | |
|--------|------------------|--------------|----------|---------|-------|--|
| SYMBOL | MBOL MILLIMETERS | | INC | | | |
| | MIN. | MAX. | MIN. | MAX. | NOTES | |
| A | 3,56 | 4.82 | .140 | .190 | | |
| A1 | 0.51 | 1.40 | .020 | .055 | | |
| A2 | 2.04 | 2.92 | .080 | .115 | | |
| b | 0.38 | 1,01 | .015 | .040 | | |
| b1 | 0.38 | 0.96 | .015 | .038 | 5 | |
| b2 | 1,15 | 1,77 | .045 | .070 | | |
| b3 | 1.15 | 1.73 | .045 | .068 | | |
| С | 0.36 | 0.61 | .014 | .024 | | |
| c1 | 0.36 | 0.56 | .014 | .022 | 5 | |
| | | | | | | |
| D | 14.22 | 16.51 | .560 | .650 | 4 | |
| D1 | 8.38 | 9.02 | .330 | .355 | | |
| D2 | 12.19 | 12.88 | .480 | .507 | 7 | |
| E | 9.66 | 10.66 | .380 | .420 | 4,7 | |
| E1 | 8.38 | 8.89 | .330 | .350 | 7 | |
| е | 2,54 BSC | | .100 BSC | | | |
| e1 | 5. | 08 | ,200 | BSC | | |
| H1 | 5.85 | 6.55 | .230 | .270 | 7,8 | |
| L | 12.70 | 14.73 | .500 | .580 | | |
| L1 | - | 6.35 | - | .250 | 3 | |
| øΡ | 3,54 | 4.08 | .139 | ,161 | | |
| Q | 2.54 | 3,42 | .100 | .135 | | |
| Ø | 90*- | -93 * | 90*- | 90'-93' | | |

LEAD ASSIGNMENTS

- HEXFET
- 1.- GATE 2.- DRAIN 3.- SOURCE

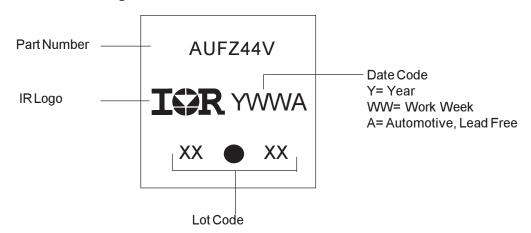
IGBTs, CoPACK

1.- GATE 2.- COLLECTOR 3.- EMITTER

DIODES

- 1,- ANODE/OPEN 2.- CATHODE 3.- ANODE

TO-220AB Part Marking Information



Note: For the most current drawing please refer to IR website at http://www.irf.com/package/

International
TOR Rectifier

Ordering Information

| Base part | Package Type | Standard Pack | | Complete Part Number |
|-----------|--------------|---------------|----------|----------------------|
| | | Form | Quantity | |
| AUIRFZ44V | TO-220 | Tube | 50 | AUIRFZ44V |

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11